November 1992 Revised April 2005

74VHC244 Octal Buffer/Line Driver with 3-STATE Outputs

General Description

FAIRCHILD

SEMICONDUCTOR

The VHC244 is an advanced high speed CMOS octal bus buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC244 is a non-inverting 3-STATE buffer having two active-LOW output enables. These devices are designed to be used as 3-STATE memory address drivers, clock drivers, and bus oriented transmitter/receivers.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed: t_{PD} = 3.9ns (typ) at V_{CC} = 5V
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.6V (typ)
- \blacksquare Low power dissipation: I_{CC} = 4 μA (max) @ T_A = 25°C
- Pin and function compatible with 74HC244

Ordering Code:

Order Number	Package Number	Package Description						
74VHC244M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide						
74VHC244SJ	M20D	Pb-Free 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide						
74VHC244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide						
74VHC244N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide						
Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.								

Pb-Free package per JEDEC J-STD-020B.

Logic Symbol



Connection Diagram



© 2005 Fairchild Semiconductor Corporation DS011522

Pin Descriptions

74VHC244

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	3-STATE Output Enable Inputs
I ₀ –I ₇	Inputs
O ₀ –O ₇	3-STATE Outputs

Truth Tables

Inp	uts	Outputs					
OE ₁	I _n	(Pins 12, 14, 16, 18)					
L	L	L					
L	н	н					
н	х	Z					
Inp	uts	Outputs					
Inp OE ₂	uts I _n	Outputs (Pins 3, 5, 7, 9)					
-							
-							

H = HIGH Voltage Level L = LOW Voltage Level I = Immaterial Z = High Impedance

Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Input Voltage (VIN)	-0.5V to +7.0V
DC Output Voltage (V _{OUT})	–0.5V to V _{CC} + 0.5V
Input Diode Current (I _{IK})	–20 mA
Output Diode Current (I _{OK})	±20 mA
DC Output Current (I _{OUT})	±25 mA
DC V _{CC} /GND Current (I _{CC})	±75 mA
Storage Temperature (T _{STG})	-65°C to +150°C
Lead Temperature (TL)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V _{CC})	2.0V to 5.5V
Input Voltage (V _{IN})	0V to +5.5V
Output Voltage (V _{OUT})	0V to V_{CC}
Operating Temperature (T _{OPR})	-40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
$V_{CC} = 3.3V \pm 0.3V$	0 ns/V ~ 100 ns/V
$V_{CC} = 5.0V \pm 0.5V$	0 ns/V ~ 20 ns/V

74VHC244

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC}	$T_A = 25^{\circ}C$			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions	
		(V)	Min	Тур	Max	Min	Max	Units	Conditions	
V _{IH}	HIGH Level	2.0	1.5			1.5		V		
	Input Voltage	3.0 - 5.5	0.7 V _{CC}			0.7 V _{CC}		v		
V _{IL}	LOW Level	2.0			0.5		0.5	V		
	Input Voltage	3.0 - 5.5			0.3 V _{CC}		0.3 V _{CC}	v		
V _{OH}	HIGH Level	2.0	1.9	2.0		1.9			$V_{IN} = V_{IH}$	$I_{OH}=-50~\mu A$
	Output Voltage	3.0	2.9	3.0		2.9		V	or V _{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		$I_{OH} = -4 \text{ mA}$
		4.5	3.94			3.80		v		I _{OH} = -8 mA
V _{OL}	LOW Level	2.0		0.0	0.1		0.1		$V_{IN} = V_{IH}$	I _{OL} = 50 μA
	Output Voltage	3.0		0.0	0.1		0.1	V	or V _{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		$I_{OL} = 4 \text{ mA}$
		4.5			0.36		0.44	v		I _{OL} = 8 mA
I _{OZ}	3-STATE Output	5.5			±0.25		±2.5	μA	$V_{IN} = V_{IH} $	or V _{IL}
	Off-State Current								$V_{OUT} = V_{C}$	_C or GND
I _{IN}	Input Leakage Current	0 - 5.5			±0.1		±1.0	μA	V _{IN} = 5.5V or GND	
I _{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	$V_{IN} = V_{CC}$	or GND

Noise Characteristics

Symbol	Parameter	V _{cc}	T _A = 25°C		Units	Conditions	
Cymbol	r didificter	(V)	Тур	Limits	onno	Conditions	
V _{OLP}	Quiet Output Maximum	5.0	0.6	0.9	V	C _L = 50 pF	
(Note 3)	Dynamic V _{OL}						
V _{OLV}	Quiet Output Minimum	5.0	-0.6	-0.9	V	C _L = 50 pF	
(Note 3)	Dynamic V _{OL}						
VIHD	Minimum HIGH Level	5.0		3.5	V	C _L = 50 pF	
(Note 3)	Dynamic Input Voltage						
VILD	Maximum HIGH Level	5.0		1.5	V	C _L = 50 pF	
(Note 3)	Dynamic Input Voltage						

Note 3: Parameter guaranteed by design.

44
S
Ť
74

AC Electrical Characteristics

Symbol	Parameter	V _{CC} (V)	$T_A = 25^{\circ}C$			$T_A = -40^{\circ}$	C to +85°C	Units	Conditions	
			Min	Тур	Max	Min	Max	Units	Conditions	
t _{PLH}	Propagation Delay	$\textbf{3.3}\pm\textbf{0.3}$		5.8	8.4	1.0	10.0	ns		C _L = 15 p
t _{PHL}	Time			8.3	11.9	1.0	13.5	115		$C_L = 50 \mu$
		$\textbf{5.0} \pm \textbf{0.5}$		3.9	5.5	1.0	6.5	ns	1	$C_L = 15 \mu$
				5.4	7.5	1.0	8.5	115		$C_L = 50 \mu$
t _{PZL}	3-STATE Output	$\textbf{3.3}\pm\textbf{0.3}$		6.6	10.6	1.0	12.5	ns		C _L = 15 p
t _{PZH}	Enable Time			9.1	14.1	1.0	16.0	115	$R_1 = 1 k\Omega$	C _L = 50 p
		5.0 ± 0.5		4.7	7.3	1.0	8.5	ns	17 - 1 172	$C_L = 15 \mu$
		J.0 ± 0.J		6.2	9.3	1.0	10.5	115		$C_L = 50 \mu$
t _{PLZ}	3-STATE Output	$\textbf{3.3}\pm\textbf{0.3}$		10.3	14.0	1.0	16.0	ns	$R_L = 1 \ k\Omega$	$C_L = 50 \mu$
t _{PHZ}	Disable Time	$\textbf{5.0} \pm \textbf{0.5}$		6.7	9.2	1.0	10.5	113		$C_{L} = 50 p$
t _{OSLH}	Output to Output	$\textbf{3.3}\pm\textbf{0.3}$			1.5		1.5	ns	(Note 4) C _L	C _L = 50 p
t _{OSHL}	Skew	5.0 ± 0.5			1.0		1.0	. 115	(14010 4)	$C_{L} = 50 p$
CIN	Input Capacitance			4	10		10	pF	$V_{CC} = Ope$	en
C _{OUT}	Output Capacitance			6				pF	V _{CC} = 5.0\	/
CPD	Power Dissipation Capacitance			19				pF	(Note 5)	

 $\textbf{Note 4:} Parameter guaranteed by design. \ t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|; \ t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|.$

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (OPR.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per bit).









ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC